

Vishay General Semiconductor

# **Dual Common-Cathode Schottky Rectifier**



MAJOR RATINGS AND CHARACTERISTICS						
I <sub>F(AV)</sub>	30 A					
V <sub>RRM</sub>	35 V to 60 V					
I <sub>FSM</sub>	200 A					
V <sub>F</sub>	0.60 V, 0.65 V					
T <sub>j</sub> max.	175 °C					

#### **FEATURES**





- Lower power losses, high efficiency
- · Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Solder Dip 260 °C, 40 seconds
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, free-wheeling diodes, dc-to-dc converters or polarity protection application.

### **MECHANICAL DATA**

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated (E3 Suffix) leads, solderable per J-STD-002B and JESD22-B102D

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	MBR3035PT	MBR3045PT	MBR3050PT	MBR3060PT	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	35	45	50	60	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	35 45		50	60	V	
Maximum DC blocking voltage	$V_{DC}$	35	45	50	60	V	
Maximum average forward rectified current (see Fig. 1)	I <sub>F(AV)</sub>	30					
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	200 A					
Peak repetitive reverse surge current per diode (1)	I <sub>RRM</sub>	2.0 1.0			Α		
Voltage rate of change at (rated V <sub>R</sub> )	dv/dt	10000				V/µs	
Operating junction temperature range	$T_J$	- 65 to + 150			°C		
Storage temperature range	T <sub>STG</sub>	- 65 to + 175			°C		

#### Note:

(1) 2.0  $\mu$ s pulse width, f = 1.0 kHz

# MBR3035PT thru MBR3060PT

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS	SYMBOL	L MBR3035PT MBR3045PT		MBR3050PT	MBR3060PT	UNIT	
Maximum instantaneous forward voltage per diode (1)	$ \begin{aligned} I_F &= 20 \text{ A}, & T_C &= 25 ^\circ\text{C} \\ I_F &= 20 \text{ A}, & T_C &= 125 ^\circ\text{C} \\ I_F &= 30 \text{ A}, & T_C &= 25 ^\circ\text{C} \\ I_F &= 30 \text{ A}, & T_C &= 125 ^\circ\text{C} \end{aligned} $	V <sub>F</sub>	- 0.60 0.76 0.72		0.75 0.65 - -		٧	
Maximum instantaneous reverse current at rated DC blocking voltage per diode (1)	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	I <sub>R</sub>	1.0 60				-	mA

#### Note:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER SYMBOL MBR3035PT MBR3045PT MBR3050PT MBR3060PT UNIT					UNIT	
Thermal resistance from junction to case per diode	$R_{\theta JC}$	1.4 °C			°C/W	

ORDERING INFORMATION							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-247AD	MBR3045PT-E3/45	6.13	45	30/Tube	Tube		

### **RATINGS AND CHARACTERISTICS CURVES**

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise specified})$ 

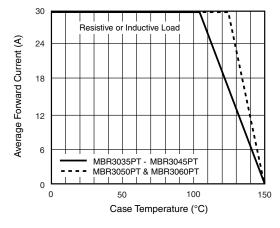


Figure 1. Forward Current Derating Curve

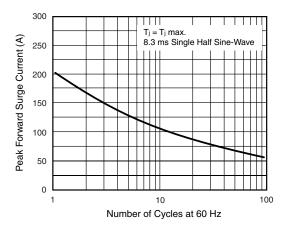


Figure 2. Maximum Non-Repetitive Peak Forward Surge **Current Per Diode** 

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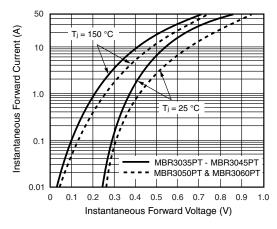


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

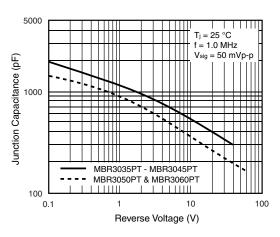


Figure 5. Typical Junction Capacitance Per Diode

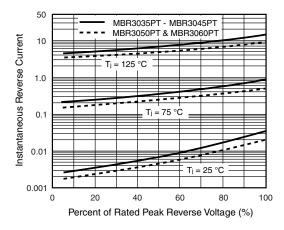


Figure 4. Typical Reverse Characteristics Per Diode

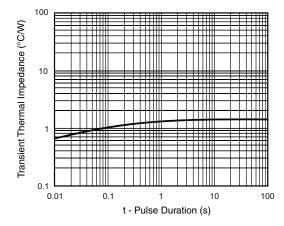
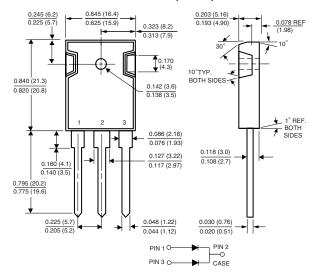


Figure 6. Typical Transient Thermal Impedance Per Diode

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### TO-247AD (TO-3P)



## **Legal Disclaimer Notice**



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